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Vishay Siliconix

Automotive P-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	-100				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0190				
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0222				
I _D (A)	-93				
Configuration	Single				
Package	TO-263				

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





	G O	S D
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ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V_{DS}	-100	V		
Gate-Source Voltage		V_{GS}	± 20	V		
Continuous Drain Current	T _C = 25 °C	L	-93			
Continuous Diain Current	T _C = 125 °C	I _D	-53			
Continuous Source Current (Diode Conduction) ^a		I _S	-120	Α		
Pulsed Drain Current b		I _{DM}	-200			
Single Pulse Avalanche Current		I _{AS}	-70			
Single Pulse Avalanche Energy L = 0.1 mH		E _{AS}	245	mJ		
Maximum Power Dissipation ^b	T _C = 25 °C	D	375	W		
waxiinuiii Fowei Dissipation -	T _C = 125 °C	P _D	125	VV		
Operating Junction and Storage Temperature Range		T_J,T_stg	-55 to +175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient PCB Mount ^c		R_{thJA}	40	°C/W		
Junction-to-Case (Drain)		R_{thJC}	0.4	C/VV		

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static					•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-100	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -100 V	-	-	-1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -100 V, T _J = 125 °C	-	-	-50	μΑ	
		$V_{GS} = 0 V$	V _{DS} = -100 V, T _J = 175 °C	-	-	-250	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≤ -5 V	-93	-	-	Α	
		V _{GS} = -10 V	I _D = -30 A	-	0.0155	0.0190		
Drain-Source On-State Resistance a	B	V _{GS} = -10 V	I _D = -30 A, T _J = 125 °C	-	-	0.0342	Ω	
Dialii-Source Oil-State nesistance *	R _{DS(on)}	V _{GS} = -10 V	I _D = -30 A, T _J = 175 °C	-	-	0.0432		
		V _{GS} = -4.5 V	I _D = -20 A	-	0.0177	0.0222		
Forward Transconductance b	9fs	V _{DS} =	V _{DS} = -15 V, I _D = -30 A		50	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	10 800	14 100	pF	
Output Capacitance	Coss	$V_{GS} = 0 V$	V _{DS} = -25 V, f = 1 MHz	-	800	1100		
Reverse Transfer Capacitance	C _{rss}			-	650	850		
Total Gate Charge ^c	Qg			-	220	350		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = -10 \text{ V}$	$V_{DS} = -50 \text{ V}, I_D = -50 \text{ A}$	-	37	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	51	-		
Gate Resistance	R_g	f = 1 MHz		1	2.2	3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}				20	30		
Rise Time ^c	t _r	$V_{DD} = -50 \text{ V}, R_L = 1 \Omega$ $I_D \cong -50 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		-	21	35		
Turn-Off Delay Time ^c	t _{d(off)}			-	110	175	ns	
Fall Time ^c	t _f			-	30	50		
Source-Drain Diode Ratings and Chara	cteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	-200	Α	
Forward Voltage	V _{SD}	I _F = -70 A, V _{GS} = 0 V			-0.885	-1.5	V	

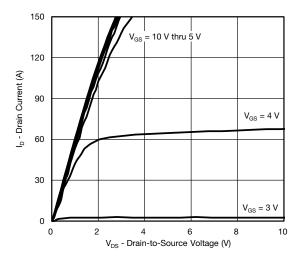
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

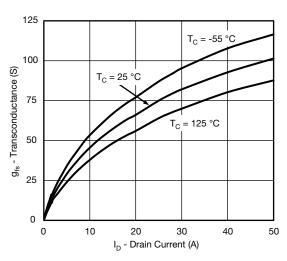
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



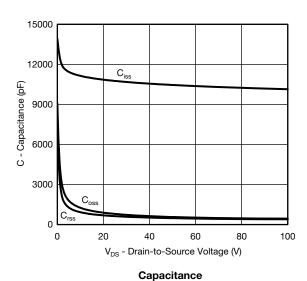
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

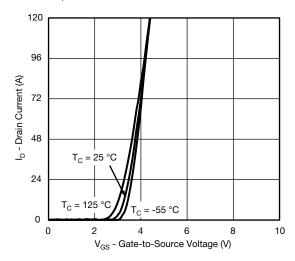


Output Characteristics

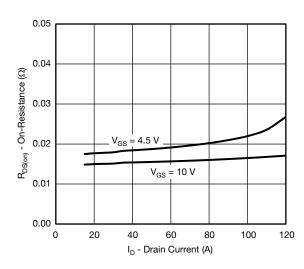


Transconductance

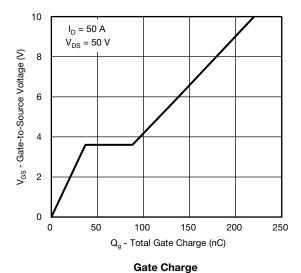




Transfer Characteristics

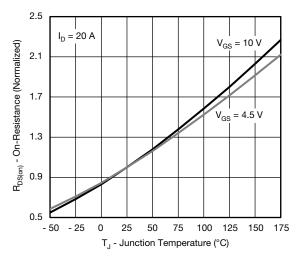


On-Resistance vs. Drain Current

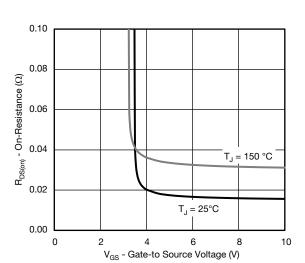




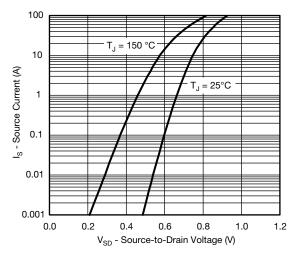
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



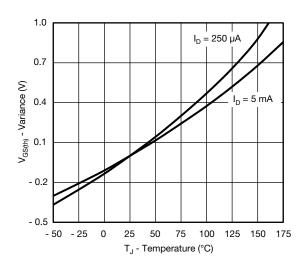
On-Resistance vs. Junction Temperature



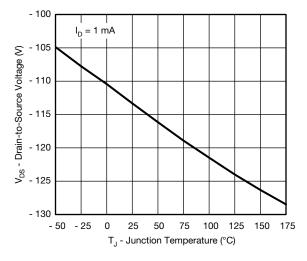
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage

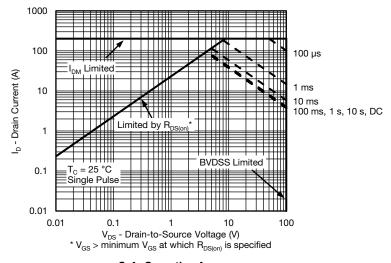


Drain Source Breakdown vs. Junction Temperature

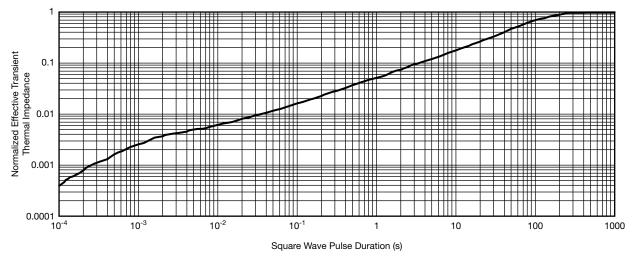
For technical questions, contact: automostech



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



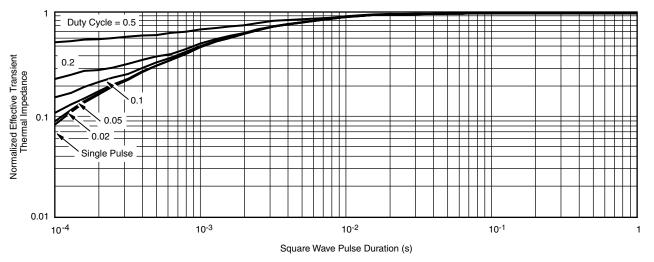
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

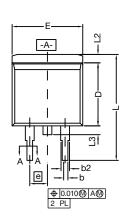
Note

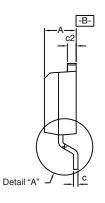
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

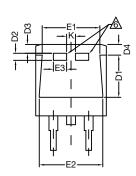
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TO-263 (D²PAK): 3-LEAD

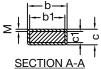








DETAIL A (ROTATED 90°)



<u> </u>	b	
2 T	ਹ <i>ੀ </i>	
	SECTION A-4	1

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

	INCHES		MILLIN	METERS	
DIM.		MIN.	MAX.	MIN.	MAX.
Α		0.160	0.190	4.064	4.826
	b	0.020	0.039	0.508	0.990
	b1	0.020	0.035	0.508	0.889
	b2	0.045	0.055	1.143	1.397
c*	Thin lead	0.013	0.018	0.330	0.457
C	Thick lead	0.023	0.028	0.584	0.711
c1	Thin lead	0.013	0.017	0.330	0.431
CI	Thick lead	0.023	0.027	0.584	0.685
	c2	0.045	0.055	1.143	1.397
	D	0.340	0.380	8.636	9.652
	D1	0.220	0.240	5.588	6.096
	D2	0.038	0.042	0.965	1.067
	D3	0.045	0.055	1.143	1.397
	D4	0.044	0.052	1.118	1.321
	Е	0.380	0.410	9.652	10.414
	E1	0.245	-	6.223	=
	E2	0.355	0.375	9.017	9.525
	E3	0.072	0.078	1.829	1.981
	е	0.100) BSC	2.54	BSC
K		0.045	0.055	1.143	1.397
L		0.575	0.625	14.605	15.875
L1		0.090	0.110	2.286	2.794
L2		0.040	0.055	1.016	1.397
L3		0.050	0.070	1.270	1.778
	L4	0.010 BSC		0.254 BSC	
	М	-	0.002	-	0.050
ECN: T13-0707-Rev. K, 30-Sep-13					

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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